**TECHNICAL DATA** 

# T-33-11

## **MRF450** MRF450A

### The RF Line

#### NPN SILICON RF POWER TRANSISTORS

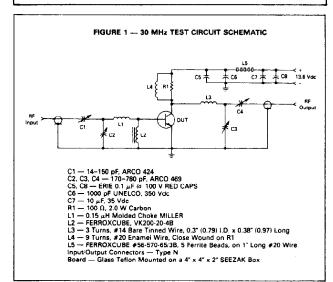
. . . designed for power amplifier applications in industrial, commercial and amateur radio equipment to 30 MHz.

 Specified 12.5 Volt, 30 MHz Characteristics — Output Power = 50 Watts Minimum Gain = 11 dB Efficiency = 50%

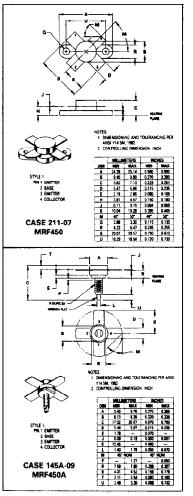
Rating	Symbol	Value	Unit Vdc	
Collector-Emitter Voltage	VCEO	20		
Collector-Base Voltage	VCBO	40	Vdc	
Emitter-Base Voltage	VE BO	4.0	- Vdc	
Collector Current - Continuous	'C	7.5	Adc	
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	115 0.66	Watts W/ <sup>O</sup> C	
Storage Temperature Range	₹stg	-65 to +150	°¢	

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermai Resistance, Junction to Case	R <sub>θ</sub> JC	1.53	°C/W
		L	L

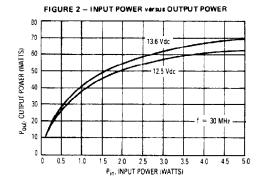


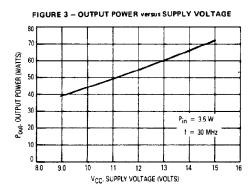
### 50 W - 30 MHz RF POWER **TRANSISTORS NPN SILICON**



ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	·				
Collector-Emitter Breakdown Voltage	V(BR)CEO	20	-		Vdc
Collector-Emitter Breakdown Voltage (I C = 20 mAdc, VBE = 0)	V(BR)CES	40	-	-	Vdc
Collector-Base Breakdown Voltage	V(BR)CBO	40	-	-	Vdc
Emitter Base Breakdown Voltage (IE = 10 mAdc, IC = 0)	V(BR)EBO	4.0	-	-	Vdc
ON CHARACTERISTICS			<del></del>		-
DC Current Gain (IC = 1.0 Adc, VCE = 5.0 Vdc)	µŁE	10	-	_	-
DYNAMIC CHARACTERISTICS					<del></del>
Output Capacitance (V <sub>CB</sub> = 15 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	Сор	_	-	200	ρF
FUNCTIONAL TESTS (Figure 1)			•		<del></del>
Common-Emitter Amplifier Power Gain (VCC = 13.6 Vdc, P <sub>OUt</sub> = 50 W, I <sub>C</sub> (max) = 6.13 Adc, f = 30 MHz)	Gp€	11	15	_	dB
Collector Efficiency (V <sub>CC</sub> = 13.6 Vdc, P <sub>out</sub> = 50 W, I <sub>C</sub> (max) = 6.13 Adc, f = 30 MHz)	η	50	-		*
Series Equivalent Input Impedance (V <sub>CC</sub> = 13.6 Vdc, P <sub>Out</sub> = 50 W; f = 30 MHz)	Z <sub>in</sub>	-	1.56-j.89	-	Ohms
Series Equivalent Output Impedance (VCC = 13.6 Vdc, P <sub>out</sub> = 50 W, f = 30 MHz)	Zout	-	174-j.50		Ohms





MOTOROLA RF DEVICE DATA

2-649

## This datasheet has been downloaded from:

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Datasheets for electronic components.